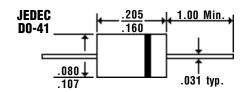


## Preliminary Data Sheet | 1.5 Amp Glass Passivated Sintered Ultra - Fast Rectifiers

# **UGPZ15A...15G Series**

## Semiconductor Description

## **Mechanical Dimensions**



## **Features**

- LOWEST COST FOR GLASS SINTERED **ULTRA - FAST CONSTRUCTION**
- LOWEST V. FOR GLASS SINTERED **ULTRA - FAST CONSTRUCTION**
- TYPICAL I<sub>R</sub> < 100 nAmps

- 1.5 AMP OPERATION @  $T_A = 55$ °C, WITH **NO THERMAL RUNAWAY**
- SINTERED GLASS CAVITY-FREE JUNCTION

Electrical Characteristics @ 25°C.  Maximum Ratings	UGPZ15A 15G Series				Units
	15A	15B	15D	15G	
Peak Repetitive Reverse VoltageV <sub>RRM</sub>	50	100	200	400	Volts
RMS Reverse Voltage $V_{R(rms)}$	35	70	140	280	Volts
DC Blocking VoltageV <sub>DC</sub>	50	100	200	400	Volts
Average Forward Rectified CurrentI $_{F(av)}$ Current 3/8" Lead Length @ $T_A = 55^{\circ}C$	1.5			Amps	
Non-Repetitive Peak Forward Surge CurrentI <sub>FSM</sub> 8.3mS, ½ Sine Wave Superimposed on Rated Load	50				Amps
Forward Voltage @ Rated Forward Current and 25°CV <sub>F</sub>	<> 1.25				Volts
Full Load Reverse CurrentI $_{\rm R}$ (av) Full Cycle Average @ ${\rm T_A}$ = 55°C	100				μAmp
DC Reverse CurrentI $_{R(max)}$		5 2			μAmp: μAmp:
Typical Junction CapacitanceC <sub>J</sub> (Note 1)		2	25		рF
Maximum Thermal ResistanceR <sub>eJA</sub> (Note 2)		3	30		°C/W
Maximum Reverse Recovery Timet <sub>RR</sub> (Note 3)		3	35		nS
Operating & Storage Temperature RangeT <sub>J</sub> , T <sub>STRG</sub>		65 t	o 175		°C

**NOTES:** 1. Measured @ 1 MHZ and applied reverse voltage of 4.0V.

- 2. Thermal Resistance from Junction to Ambient at 3/8" Lead Length, P.C. Board Mounted.
- 3. Reverse Recovery Condition  $I_F = 0.5A$ ,  $I_R = 1.0A$ ,  $I_{RR} = 0.25A$ .